

## Explaining the Unusual Photoluminescence of Semiconductor Nanocrystals Doped Via Cation Exchange

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**Abstract**

Aliovalent doping of CdSe nanocrystals (NCs) via cation exchange processes has resulted in interesting and novel observations for the optical and electronic properties of the NCs. However, despite over a decade of study, these observations have largely gone unexplained, partially due to an inability to precisely characterize the physical properties of the doped NCs. Here, electrostatic force microscopy was used to determine the static charge on individual, cation-doped CdSe NCs in order to investigate their net charge as a function of added cations. While the NC charge was relatively insensitive to the relative amount of doped cation per NC, there was a remarkable and unexpected correlation between the average NC charge and PL intensity, for all dopant cations introduced. We conclude that the changes in PL intensity, as tracked also by changes in NC charge, are likely a consequence of changes in the NC radiative rate caused by symmetry breaking of the electronic states of the nominally spherical NC due to the Coulombic potential introduced by ionized cations.

**Keywords:** semiconductor nanocrystals, aliovalent doping, cation exchange, electrostatic force microscopy, nanocrystal charge, symmetry breaking

## Paper

For decades, semiconductor nanocrystals (NCs) have been studied for their interesting electrical and optical properties,<sup>1,2,3</sup> which also make them potentially suitable for a number of applications, including solar energy conversion<sup>4,5,6</sup>, optoelectronic devices<sup>7,8,9,10</sup>, and biomedical imaging<sup>11,12,13,14</sup>. Major advances in the colloidal NC field directly arose from the ability to control the composition, size, and morphology of NCs, which is made possible by a number of different synthesis techniques.<sup>15,16</sup> Cation exchange, a chemical transformation used to modify a crystal whereby a cation from solution is inserted or exchanged with a host cation, has recently become a highly effective tool for enabling the synthesis of nanoparticles with novel chemical compositions.<sup>17,18</sup> Cation exchange has been used to synthesize novel core/shell NCs<sup>19</sup>, branched NC structures<sup>20</sup>, heterostructured nanorods<sup>21,22</sup>, and core and core/shell nanoplatelets<sup>23</sup>, NC compositions and morphologies that are otherwise unobtainable by direct synthesis.

Cation exchange has also been used to dope NCs by carefully controlling the number of cations in solution that become available for exchange.<sup>24,25</sup> Doping of NCs can also be achieved through a variety of other methods, including nucleation and growth doping<sup>26</sup>, surface treatments<sup>27,28</sup>, and etching-regrowth-doping<sup>29</sup>, but cation exchange has become one of the more popular techniques due to its relative simplicity.<sup>30</sup> Doping NCs via cation exchange is advantageous since it affords supposedly excellent control over doping levels while also allowing for undoped control samples for facile evaluation of the effects of doping on the NC.<sup>24</sup> While a number of synthesis methods and doped NC systems are available and have been studied<sup>24,25,30,31,32,33,34,35,36</sup>, many effects of doping on the photophysics of NCs are not well understood. Specifically, we focused on the cation exchange aliovalent doping of CdSe NCs with Ag<sup>+</sup> to produce series of samples that differ only by the amount of Ag added.<sup>25</sup> These Ag<sup>+</sup>

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3 doped CdSe NCs demonstrate unusual photophysics whereby a substantial increase in the  
4  
5 exciton photoluminescence (PL) intensity was observed upon doping with a small amount of  $\text{Ag}^+$   
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7 followed by a subsequent decrease in PL intensity with further increasing doping amounts.<sup>25</sup>  
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10 Additionally, a dopant “defect” PL peak also grew in to the red of the main band-edge peak with  
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12 increasing dopant amount. Recently, it was found that introducing  $\text{Ag}^+$  during a one-pot  
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14 synthesis/cation exchange procedure resulted in a broad, intense dopant PL peak with no exciton  
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16 PL.<sup>37</sup> These divergent behaviors exemplify the need for greater understanding about the cation  
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18 exchange doping process of NCs in general, and in particular, about how  $\text{Ag}^+$  dopants affect NC  
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23 PL.

24 Doping of NCs via cation exchange could result in the creation of locally charged  
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26 particles depending on the nature of the doping process.<sup>29</sup> For example, the introduction of the  
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28 aliovalent  $\text{Ag}^+$  impurity ion as an interstitial dopant would cause a locally positive charge inside  
29  
30 the NC. Conversely, the introduction of  $\text{Ag}^+$  as a substitutional dopant would result in a locally  
31  
32 negative charge as the  $\text{Cd}^{2+}$  ions are displaced from the crystal lattice. We hypothesized that  
33  
34 direct measurements of the charged state of the doped NCs as a function of the added  $\text{Ag}^+$  per  
35  
36 NC could provide insight into the unusual exciton photoluminescence properties reported for  $\text{Ag}^+$   
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38 doped CdSe NCs,<sup>25</sup> as well as provide a greater understanding of the cation exchange doping  
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43 process itself.

44 Here we report a dramatic and unexpected relationship between the charges of individual  
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46 CdSe NCs doped with  $\text{Ag}^+$  and the photoluminescence properties for these NC samples.  
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48 Specifically, we found that as the number of dopant ions per NC was varied, the subsequent  
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50 changes in the ensemble exciton PL intensity and the average electrostatic charge per NC as  
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52 determined with electrostatic force microscopy (EFM) were highly correlated. Conversely, the  
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3 average charge measured per NC did not seem to depend strongly on the quantity of dopant ions  
4 added during the cation exchange process. Indeed, despite adding between one and hundreds of  
5  $\text{Ag}^+$  dopant ions on average per CdSe NC, the average charge measured using EFM never varied  
6 by more than  $\pm 1e$ . We further show this fixed and stable charge results from both the cation  
7 exchange process (i.e. replacing a +2 cation with a +1 cation and/or a +1 cation interstitial), and  
8 the attraction of counterions to the charged NC surface. By calculating the radiative rate for  
9 CdSe NCs of various configurations of charges near the surface of the NC, we accurately  
10 modeled both the changes in the charge state of the NC and the changes in PL intensity, thus  
11 showing that the combination of surface and interior charges due to doping can explain the  
12 observed photophysical behavior.  
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26 CdSe NCs were made using variations on known synthesis procedures<sup>38,39</sup> and were then  
27 doped with  $\text{Ag}^+$ ,  $\text{Li}^+$ , or  $\text{Ca}^{2+}$  ions using a cation exchange procedure adapted from Sahu *et al.*<sup>25</sup>  
28 The amount of dopant introduced into the NC was quantified using inductively coupled plasma  
29 mass spectrometry (ICP-MS). Absorption spectroscopy showed little to no change in the  
30 absorbance with increasing dopant concentration, even at extremely high doping amounts, as  
31 seen in Figure 1a. Enhancement in the exciton PL intensity with increasing added  $\text{Ag}^+$  was  
32 sometimes observed (though not always) while a dopant peak consistently grew in to the red of  
33 the main peak with increasing  $\text{Ag}^+$  added, as evident in Figure 1b. These trends in PL spectra  
34 also agree with the trends reported for  $\text{Ag}^+$  doped CdSe NCs in Reference 25. From dark-field,  
35 high-resolution scanning transmission electron microscopy (ADF-STEM) (Figure 1c), one can  
36 see that the size, shape, and crystal structure of the NCs also remain unchanged with added  
37 dopants, as expected for doping via cation exchange processes.  
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Similar optical spectra were measured for doping controls in which the CdSe NCs were doped with  $\text{LiNO}_3$ ,  $\text{Ca}(\text{NO}_3)_2$ , and  $\text{AgClO}_4$  (Supporting Information Figures S12 and S13). Importantly, similar trends in absorbance and PL spectra were observed for these control samples. Thus, the exciton PL changes observed for  $\text{AgNO}_3$  doping are not due exclusively to the  $\text{Ag}^+$  cations acting as internal dopants within the NCs. Rather, the changes in exciton PL are due to the mere presence of a charged cation in the interior or on the surface of the NC. Note that while we observed changes in the exciton PL peak intensity with all dopants, the red-shifted dopant PL peak was only present with introduction of the  $\text{Ag}^+$ , both with  $\text{AgNO}_3$  and  $\text{AgClO}_4$  added, but not the  $\text{Li}^+$  or  $\text{Ca}^{2+}$  cations. This is expected behavior as this peak is attributed to the presence of the  $\text{Ag}^+$  as a dopant within the CdSe lattice.<sup>25,37</sup>

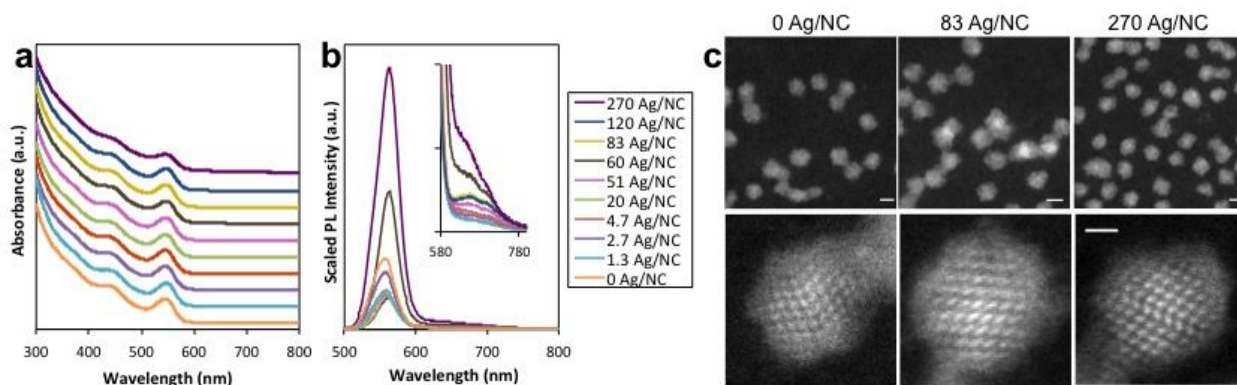


Figure 1. (a) Absorbance and (b) PL spectra for a series of  $\text{Ag}^+$  doped CdSe NCs. The inset in (b) magnifies the weak PL feature near 700 nm. (c) ADF-STEM images for three samples with different doping levels, (left) 0 Ag/NC, (middle) 83 Ag/NC, (right) 270 Ag/NC. Scale bars in the top images represent 3 nm and scale bar in the bottom image represents 1 nm.

EFM is an exceptionally sensitive technique that can be used to measure the charged state of single NCs to less than 1 elementary charge  $e$ .<sup>40,41,42,43,44</sup> EFM is a modification of atomic force microscopy that works by measuring the long-range electrostatic forces between a conductive cantilever and a conductive substrate. In our EFM experiment, a first pass of the

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3 cantilever measures the topography of the sample. In a subsequent second pass, the tip is lifted  
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5 off the surface and scanned at a constant height under an applied AC and DC voltage, and  
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7 thereby is sensitive to long-range capacitive and Coulombic forces (See SI for a detailed  
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9 description of EFM).<sup>41,43</sup>  
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12 Representative samples of EFM images are shown in Figure 2 for two different Ag<sup>+</sup>  
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14 doped CdSe NC samples with 0 Ag/NC (top) and 0.5 Ag/NC (bottom). Images 2a and 2e are  
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16 standard AFM height images and are used to identify the location and heights of the individual  
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18 NCs. Images 2b and 2f correspond to the changes in cantilever resonance frequency at the first  
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20 harmonic of the AC voltage  $\Delta v(\omega)$ , from which the charges of the individual NCs located in the  
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22 height image are calculated (See SI for details of calculation). Images 2c and 2g correspond to  
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24 changes in the cantilever resonance frequency at the second harmonic of the AC voltage  $\Delta v(2\omega)$   
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26 and give information that depends on the dielectric constant of the individual NCs. Our  
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28 measured dielectric constants for individual NCs were consistent with previously reported values  
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30 for CdSe<sup>41,45,46</sup>, suggesting accurate modeling of the tip-substrate capacitance. Each NC sample  
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32 exhibited a distribution of calculated charges. As shown in Figure 2f, the NCs doped with about  
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34 0.5 Ag/NC are predominantly bright, indicating negatively charged NCs. Conversely, the NCs  
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36 with 0 Ag/NC shown in Figure 2b are less bright, representing more neutral NCs. The NCs also  
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38 contain a distribution in measured charge per NC as shown in the histograms, Figures 2d and 2h.  
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40 EFM images for this entire doping series are shown in Fig. S7.  
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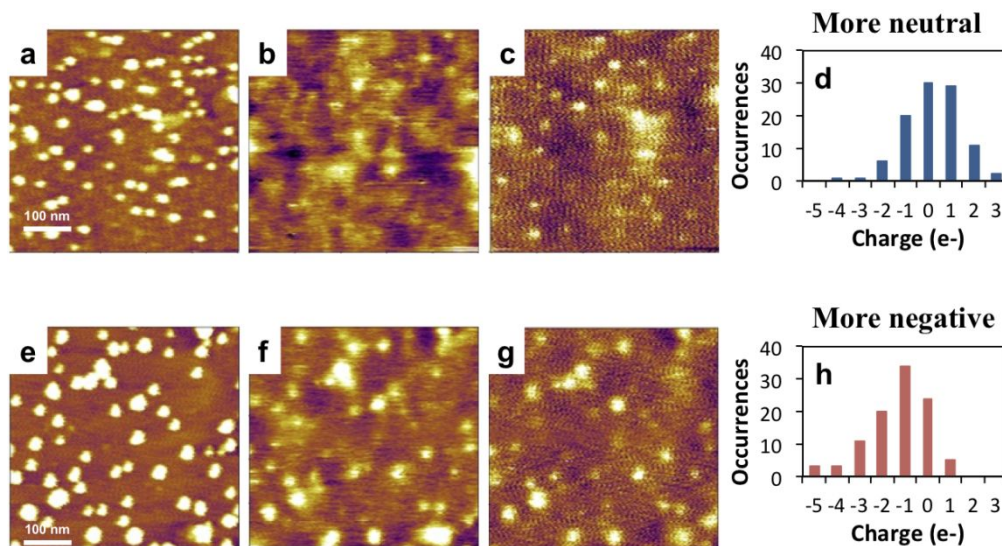


Figure 2. EFM images for samples with 0 Ag/NC (top) and 0.5 Ag/NC (bottom). (a,e) AFM height images, (b,f) charge images measuring cantilever response at  $\Delta v(\omega)$ , (c,g) dielectric constant images measuring cantilever response at  $\Delta v(2\omega)$ . (d,h) Histograms showing the distributions of NC charges in the corresponding EFM images.

For a given dopant quantity of Ag/NC, we used the mean value of the charge distribution to determine the average charge per NC. We then used these average values to plot the average charge per NC as a function of doping amount, as presented in Figure 3a. Similar data were acquired for the doping control samples  $\text{AgClO}_4$ ,  $\text{LiNO}_3$ , and  $\text{Ca}(\text{NO}_3)_2$  and are shown in Figure 3c. While CdSe NCs as synthesized are nominally neutral<sup>41</sup>, after the washing and rinsing process with no cation exchange (i.e. the undoped sample), the average charge per NC as measured with EFM ranged from -0.5 to -2.0 e. We presume that this negative charge results from a slight loss of metal carboxylate passivating ligands from the NC surface during the exposure to ethanol, leaving unpassivated Se anions.<sup>47</sup> Note that with respect to the average charge per NC, we could not find a simple monotonic trend with increasing dopant added, nor did we find consistent relationships between charge and dopant level among several doping trials. Corresponding plots of the maximum PL intensities vs. dopant concentration for these same sets of samples are also given in Figure 3 (b, d). Over several trials, we generally (but not

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3 always) observed an initial increase in exciton PL intensity with added dopant, consistent with  
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5 previous reports on Ag<sup>+</sup> doping of CdSe NCs Sahu *et al.*<sup>25</sup> Note that we did not observe an  
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7 enhanced PL intensity due to Ag doping for every trial and there was no consistent trend in  
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9 exciton PL intensity with respect to average Ag/NC amounts (see Supporting Information  
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11 Figures S8-S11). Additionally, some trials show an overall decrease in the PL intensity,  
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13 attributed to the substantial washing and workup procedures used for the doping process.  
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15 Further, the inability to reproducibly create homogeneously doped NCs with this post-synthesis  
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17 cation exchange process makes it impossible to obtain identical results across all doping trials.  
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19 We believe that the inconsistency and non-monotonic nature of the PL intensity enhancement  
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21 with added Ag is due to the absence of an asymmetrical charge placement around the NC, as  
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23 discussed subsequently.  
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29 In comparing the EFM and the PL data for the Ag<sup>+</sup> doped CdSe samples (Figures 3a and  
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31 b) we found a remarkable correlation between the average charge per NC and the exciton PL  
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33 intensity. Increases or decreases in NC charge tracked similar increases or decreases in the PL  
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35 intensity, as the amount of Ag<sup>+</sup> was varied. It is important to note that the EFM and PL  
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37 experiments are completely unrelated except for the sample: the former is an average over  
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39 hundreds of NCs that are dried on a graphene substrate and the latter is an ensemble  
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41 measurement in solution. This result suggests that the PL intensity changes seen across dopant  
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43 levels are intimately associated with a charging event due to the introduction of anions and  
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45 cations to the NCs. Considering the significant evidence that the Ag<sup>+</sup> impurity ions are  
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47 introduced interstitially with eventual conversion to substitutional dopants<sup>25,48,49</sup> and the lack of a  
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49 trend in the charge with respect to the dopant amount, the PL intensity changes are likely not  
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51 exclusively due to the internal dopants. Further evidence for this hypothesis comes from the  
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control doping samples, which showed a clear enhancement in the exciton PL intensity upon introduction of the other cations that do not necessarily dope the NC lattice (Figure 3d). These  $\text{Li}^+$  and  $\text{Ca}^{2+}$  doped CdSe samples also showed similar charge/PL correlations as when doping with  $\text{Ag}^+$ .

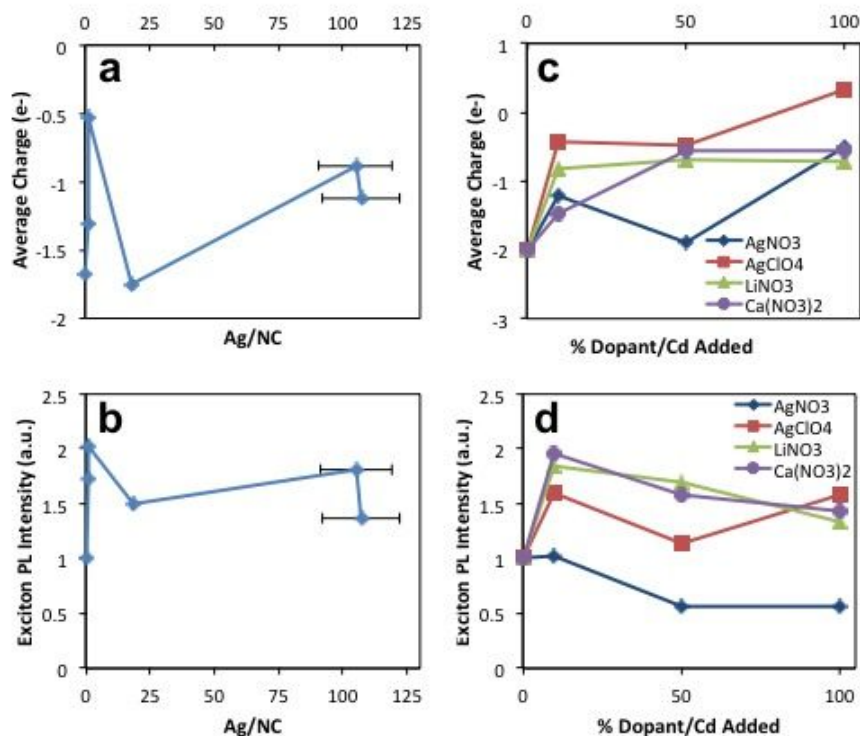


Figure 3. (a,c) Average charges for (a) the trial of  $\text{Ag}^+$  doping and (c) the series of control doping trials with  $\text{AgNO}_3$ ,  $\text{AgClO}_4$ ,  $\text{LiNO}_3$ , and  $\text{Ca}(\text{NO}_3)_2$ . (b,d) The maximum exciton PL intensities for (b) a trial of  $\text{Ag}^+$  doping and (d) a series of control doping trials.

In total, the EFM and PL data suggest that simply exposing NCs to anions and cations during the cation exchange process, including the  $\text{Ag}^+$  ions, is actually causing the PL/charge changes that we and others have observed. Thus, the PL enhancement is not a direct result of dopant type, but rather a result of passivation of the NC surface and/or the creation of an

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3 electrostatic field inside the NC, both possibilities suggested by electrochemical measurements  
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5 of the  $\xi$ -potential for similar systems.<sup>50</sup>  
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8 We propose that the changes in exciton PL and the demonstrated correlation between PL  
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10 intensity and average NC charge result from the effects of symmetry breaking of the NC due to  
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12 the presence of off-center fixed charges. In CdSe NCs, the lowest energy exciton state is  
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14 optically dark due to the spin selection rule.<sup>51</sup> Recent theoretical work has showed that charged  
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16 defect centers can break the NC symmetry allowing for a brightening of the lowest exciton state  
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18 in CdSe NCs.<sup>52</sup> Specifically, depending on the location of the defect centers with respect to the  
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20 NC crystal lattice orientation, the resulting breaking of inversion symmetry can lead to up to a  
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22 10-fold increase in the radiative rate, with a coinciding increase in the PL quantum yield.<sup>52</sup> This  
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24 model was then extended to consider different configurations of charge and compensating  
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26 counter-charges to investigate their effects on the radiative lifetime and PL and absorption  
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28 spectra.<sup>53</sup>  
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33 Here we modeled the Ag<sup>+</sup> doped NCs with a set of simplified configurations of positive  
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35 charges representing the Ag<sup>+</sup> dopants and negative charges representing counter-ions, as shown  
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37 in Figure 4a. Leveraging the recently developed theoretical model for the symmetry-breaking  
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39 effect of a charged center on exciton fine structure and level mixing,<sup>41,52,53</sup> we calculated using a  
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41 four-band effective mass model that incorporates exchange and axial field effects that a selection  
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43 of these structures gave an increased radiative rate over an undoped NC, with the same order of  
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45 magnitude as we and others have observed in the brightening of the NC PL (Figure 4b).<sup>25</sup> Note  
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47 that in these calculations, correctly accounting for the long-range exchange interaction, as  
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49 described in Reference 41, was necessary to properly model the changes in radiative rate.<sup>54</sup> For  
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51 the conformations in which we have unbalanced charges, such as those highlighted in green in  
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3 Figure 4a, we would also expect to see a permanent charge from EFM, whether positive or  
4 negative. Those conformations that demonstrated an increased radiative rate are the same as  
5 those for which we would expect to observe an EFM charge. Conversely, for the configurations  
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10 with balanced dopant/counter-ion charges for which we would expect to observe a neutral  
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13 particle in EFM, we found little to no increase in the radiative rate.

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15 While theory suggests the PL changes due to added charges proceed through modifying  
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17 the radiative rate of the NC, an alternative explanation is that the added ions are changing the  
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19 non-radiative rate perhaps through interactions with the NC surface. To test this possibility, we  
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21 took measurements of the NC PL lifetime and PL efficiency, which allowed for a determination  
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23 of changes in radiative and non-radiative decay rates associated with different doping levels.  
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26 Raw time-resolved single photon counting PL decay curves and information on the measured  
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28 decay rates are given in the SI in Figure S14 and Tables S1 and S2. In short, the trend in the  
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30 calculated radiative rates inferred from the time-resolved PL decays and the quantum yield  
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32 measurements better matched the changes in the relative oscillator strength for the calculated  
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34 configurations (Figure 4b). By contrast, changes in the non-radiative rate extracted from this  
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36 analysis were typically much smaller and would result in a much smaller contribution to the  
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38 overall PL enhancement if changes in the non-radiative rate were the dominant effect. Thus  
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40 overall, the combination of calculations backed by the time-resolved PL measurements provide  
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43 evidence that the PL enhancement observed for Ag<sup>+</sup> doped CdSe is a result of a radiative rate  
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45 acceleration caused by symmetry breaking and consequent brightening of the dark exciton state  
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49 by the introduced charge.  
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3 creates difficulty in consistently producing identical NC samples due to the natural  
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5 irreproducibility of the required post-processing precipitation and washing steps. Coupled with  
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7 the inability to precisely characterize and control the chemical nature of NC surfaces down to the  
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9 atomic level and the sensitivity in PL to the exact placement of the ions within and on a NC, each  
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11 sample doping set is best considered independently. Indeed, there are many combinations of  
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13 dopant ions and counterions that can lead to an enhancement in the PL intensity/increase in NC  
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15 charge. Thus it is expected that there are a wide variety of possible trends that could be observed  
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17 in PL intensity/NC charge with increasing exposure to ions. For illustration, some of these  
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19 additional configurations are expressed in the cartoon of Figure S15. Some of these  
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21 configurations (those in symmetrical arrangements) can reduce the radiative decay rate while  
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23 others (the asymmetrical configurations) can increase the rate, and thus non-monotonic  
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25 dependences in PL with respect to amount of Ag added are observed. However, at low doping  
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27 concentrations, such as with the introduction of a single charged Coulomb center, an increase of  
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29 the radiative decay rate is extracted from the analysis of time-resolved PL data, which is  
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31 qualitatively consistent with the calculated effect due to a fixed charged center.  
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38 While sample heterogeneity makes predicting the changes in charge and PL intensity  
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40 across doping levels problematic, there is a clear correlation between NC average charge and PL  
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42 intensity. The observed changes are definitely caused by the introduction of the cations, whether  
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44 as dopants that enter the NC or as charges that sit near the surface of the NCs. Scanning  
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46 transmission electron microscopy-electron energy loss spectroscopy measurements are one  
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48 possible route to locate the dopants within the NCs to parse out which configurations of Ag<sup>+</sup>  
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50 doped NCs give specific optical and charge results. Combining this physical characterization  
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52 with single molecule fluorescence studies will elucidate the effects of doping on the optical  
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3 properties of the NCs and will help to correlate the dopant quantity and location to the already  
4 established charge/PL intensity connection explained here.  
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8 In conclusion, cation dopants were introduced to CdSe NCs using a cation exchange  
9 procedure and the resulting photophysical properties were generally comparable to those of  
10 similar systems previously studied. EFM was used to characterize the charge of the doped CdSe  
11 NCs, and an unexpected and remarkable relationship between average charge and ensemble  
12 exciton PL intensity was observed. The NC samples that exhibited an exciton PL intensity  
13 enhancement had greater charge than those that were dimmer. These findings suggest that the  
14 enhancement in PL intensity previously ascribed to the Ag dopants sitting interstitially within the  
15 NC lattice might be better explained by the mere presence of a cation providing a charge that  
16 causes an electric field resulting in increased radiative decay, a proposition supported by both the  
17 experimental results and theoretical work presented here.  
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**Supporting Information Available:**

Detailed experimental methods (NC synthesis, doping, and characterization techniques), electrostatic force microscopy explanation and details, additional sample characterization data, optical and EFM data for additional Ag<sup>+</sup> doped CdSe doping sets, optical and EFM data for other impurity doped samples, and PL lifetime decay curves and lifetime fitting results for Ag<sup>+</sup> doped CdSe samples.

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